

## DESCRIPTION

The S3AF~S3MF are available in SMAF package

# FEATURES

- For surface mounted applications
- Low profile package
- Glass Passivated Chip Juntion
- Easy to pick and place
- Available in SMAF package

### **ORDERING INFORMATION**

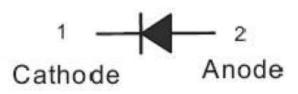
Package Type	Part Number				
	S3AF				
SMAF	S3BF				
	S3DF				
	S3GF S3JF				
					S3KF
	S3MF				
	Note	SPQ: 3,000pcs/Reel			
AiT provides all RoHS Compliant Products					

### MECHANICAL DATA

Case: SMAF

Terminals: Solderable per MIL-STD-750, Method 2026 Approx. Weight: 27mg 0.00086oz

## **PIN DESCRIPTION**





# MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

Single phase half-wave 60 Hz, resistive or inductive load, for capacitive load current derate by 20 %.										
Parameter	Symbol	S3AF	S3BF	S3DF	S3GF	S3JF	S3KF	S3MF	Unit	
Maximum Repetitive Peak Reverse	Vrrm	50	100	200	400	600	800	1000	V	
Voltage										
Maximum RMS Voltage	VRMS	35	70	140	280	420	560	700	V	
Maximum DC Blocking Voltage	$V_{\text{DC}}$	50	100	200	400	600	800	1000	V	
Maximum Average Forward Rectified										
Current at T <sub>A</sub> =65°C	F(AV)	3							A	
Peak Forward Surge Current 8.3 ms										
Single Half Sine Wave Superimposed	I <sub>FSM</sub>	100							А	
on Rated Load(JEDEC Method)										
Maximum Instantaneous Forward	VF	1.2							v	
Voltage at 3A	VF									
Maximum DC Reverse Current @T <sub>A</sub> =25°C	1_	5 250							μΑ	
at Rated DC Blocking Voltage @T <sub>A</sub> =125°C	IR									
Typical junction capacitance NOTE1	CJ	53					pF			
	D	13						°C/W		
Typical thermal resistance NOTE2	Reja	47								
Operating and Storage Temperature	TJ,	55.1.450				℃				
Range	T <sub>STG</sub>	-55 to 150					U			

Ratings at 25°C ambient temperature unless otherwise specified.

NOTE1: Measured at 1 MHz and applied reverse voltage of 4 V DC

NOTE2: Thermal resistance from junction to ambient at 0.375" (9.5 mm) lead length, P.C.B. mounted



# TYPICAL CHARACTERISTICS

#### Figure 1. Forward Current Derating Curve

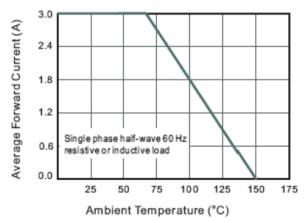
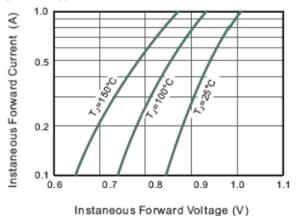


Figure 3. Typical Forward Characteristic



#### Figure 2. Typical Instaneous Reverse

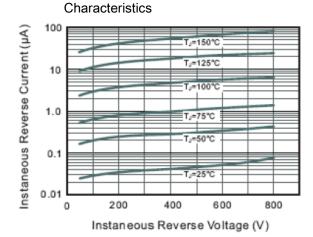
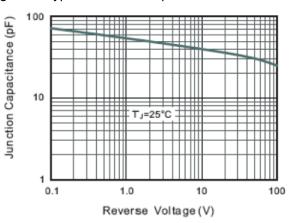


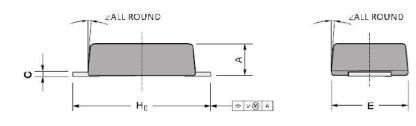
Figure 4. Typical Junction Capacitance

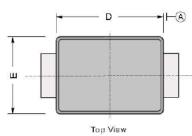


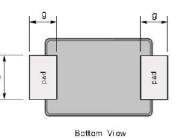


## PACKAGE INFORMATION

Dimension in SMAF Package (Unit: mm/mil) Plastic surface mounted package; 2 leads

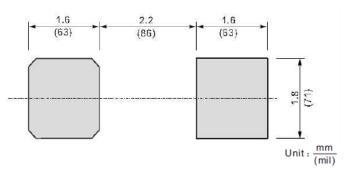






UNIT		А	С	D	E	е	g	HE	2
mm	max	1.1	0.20	3.7	2.7	1.6	1.2	4.9	
	min	0.9	0.12	3.3	2.4	1.3	0.8	4.4	<b>7</b> °
mil	max	43	7.9	146	106	63	47	193	
	min	35	4.7	130	94	51	31	173	

#### The recommended mounting pad size





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